General Description

The MAX9957 dual driver IC for automatic test equipment (ATE) memory applications offers three-level drive capability, high-speed switching, low timing dispersion, and features voltage-controlled waveform shaping to enhance edge-placement accuracy and minimize distortion. It also provides tight matching of gain and offset. The MAX9957 buffers reference voltage inputs for each channel with nominal -1V to +3.5V voltage ranges. High-speed differential control inputs, compatible with CML levels, are provided for each channel. Static power dissipation is only 1500mW per channel with nominal -5V and +7V supplies. The MAX9957 power dissipation at 2Gbps toggling is only 1550mW/channel. The MAX9957D power dissipation at 2.4Gbps is only 1850mW/channel.

The MAX9957 is available in a 10mm x 10mm x 1mm, 64-pin TQFP package with an exposed pad, inverted die pad for ease of heat removal.

Applications

Automatic Test Equipment DDR2 Memory Testers GDDR3 GDDR4

MAXIM DDR3 MEMORY DHV INPUT WAVE DTV BUFFFR MUX SHAPING DLV_ DOVS DOVL ONE OF TWO CHANNELS SHOWN MAXIM MAX9955 DUT DTV CHV CH NCH DROOP COMPENSATION CI NCL CLV COS_ COL ONE OF TWO CHANNELS SHOWN

_ Maxim Integrated Products 1

Terminator/3-Level Driver
2Gbps Toggling at 2VP-P (MAX9957)
2.4Gbps Toggling at 2VP-P (MAX9957D)
Voltage-Controlled Waveform Shaping

- Interfaces Easily With Most Logic Families
- Low Timing Dispersion

Ordering Information

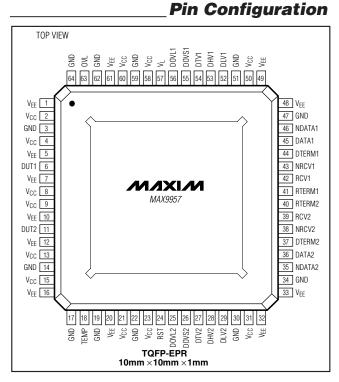
PART	TEMP RANGE	PIN-PACKAGE
MAX9957CCB-D	0°C to +70°C	64 TQFP-EPR*
MAX9957CCB+D	0°C to +70°C	64 TQFP-EPR*
MAX9957DCCB+D	0°C to +70°C	64 TQFP-EPR*

-Denotes a package containing lead(Pb).

D = Dry pack.

+Denotes a lead(Pb)-free/RoHS-compliant package.

*EPR = Exposed pad reversed (exposed pad on top of device).



For pricing, delivery, and ordering information, please contact Maxim Direct at 1-888-629-4642, or visit Maxim's website at www.maxim-ic.com.

Features

Typical Operating Circuit

ABSOLUTE MAXIMUM RATINGS

V _{CC} to GND	0.3V to +8V
VEE to GND	6V to +0.3V
V _{CC} - V _{EE}	0.3V to +14V
	0.3V to +4.1V
DUT_ to GND	2V to +4.5V
DATA_, NDATA_, RCV_, NRCV_ to GND	0.3V to 4.1V
DATA_ to NDATA_, RCV_ to NRCV	±1.5V
V _{DTERM} - V _{DATA}	+2V to -0.3V
VDTERM - VNDATA	+2V to -0.3V
VRTERM - VRCV	+2V to -0.3V
VRTERM - VNRCV	+2V to -0.3V
DTERM_, RTERM_ to GND	0.3V to +4.1V
RST to GND	0.3V to $(V_1 + 0.3V)$

DHV_, DLV_, DTV_ to GND (MAX9957)2V to +4.5V
DHV_, DLV_, DTV_ to GND (MAX9957D)1.7V to +4.5V
DOVS_, DOVL_ to GND0.3V to +4.1V
OVL to GND0.3V to $(V_L + 0.3V)$
All Other Pins to GND(V _{EE} - 0.3V) to (V _{CC} + 0.3V)
TEMP Current0.5mA to +20mA
DUT_ Current80mA to +80mA
DUT_ Short Circuit to -1V to +3.5VContinuous
Package Power Dissipation ($T_A = +70^{\circ}C$)
64-Pin TQFP-EP-IDP (derate 125mW/°C above +70°C)10W
Storage Temperature Range65°C to +150°C
Junction Temperature+125°C
Lead Temperature (soldering, 10s)+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

 $(V_{CC} = +7V, V_{EE} = -5V, V_{L} = +3.3V, V_{RTERM} = V_{DTERM} = +3.3V, V_{DHV} = +2V, V_{DLV} = 0V, V_{DTV} = +1V, V_{DOVS} = V_{DOVL} = 0V, T_{J} = +70^{\circ}C \pm 10^{\circ}C$, unless otherwise noted. All temperature coefficients are measured at T_{J} = +50^{\circ}C to +90°C.)

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	МАХ	UNITS		
DC CHARACTERISTICS (Note 1)								
Voltage Range			-1.0		+3.5	V		
Voltage Swing			0.1		4.0	V		
		DHV: V _{DHV} = 0 and 2.5V, V _{DLV} = -1V, V _{DTV} = 1.5V	0.997	1.000	1.003			
Gain (Note 2)		DTV: V _{DTV} _ = 0 and 2.5V, V _{DLV} _ = -1V, V _{DHV} _ = 3.5V	0.997	1.000	1.003	V/V		
		DLV: $V_{DHV_} = 3.5V, V_{DLV_} = 0 \text{ and } 2.5V, V_{DTV_} = 1.5V$	0.997	1.000	1.003			
		DHV: V _{DHV} = 0 and 2.5V, V _{DLV} = -1V, V _{DTV} = 1.5V		-70				
Gain Temperature Coefficient		DTV: V _{DTV} _ = 0 and 2.5V, V _{DLV} _ = -1V, V _{DHV} _ = 3.5V		-60		ppm/°C		
		DLV: V_{DHV} = 3.5V, V_{DLV} = 0 and 2.5V, V_{DTV} = 1.5V		-70				
		DHV: V _{DHV} = 2V, V _{DLV} = -1V, V _{DTV} = 1.5V			±20			
Offset		DTV: V _{DHV} = 3.5V, V _{DLV} = -1V, V _{DTV} = 1V			±20	mV		
		DLV: V _{DHV} = 3.5V, V _{DLV} = 0V, V _{DTV} = 1.5V			±20			

ELECTRICAL CHARACTERISTICS (continued)

 $(V_{CC} = +7V, V_{EE} = -5V, V_L = +3.3V, V_{RTERM} = V_{DTERM} = +3.3V, V_{DHV} = +2V, V_{DLV} = 0V, V_{DTV} = +1V, V_{DOVS} = V_{DOVL} = 0V, T_J = +70^{\circ}C \pm 10^{\circ}C$, unless otherwise noted. All temperature coefficients are measured at $T_J = +50^{\circ}C$ to $+90^{\circ}C$.)

PARAMETER	SYMBOL	CONDITIONS		MIN	ТҮР	MAX	UNITS	
		DHV: V _{DHV} = 2V, V _{DLV} = -1V, V _{DTV}	= 1.5V		-100			
Offset Temperature Coefficient		DTV: V _{DHV} = 3.5V, V _{DLV} = -1V, V _D	tv_ = 1V		-40		µV/°C	
		DLV: V _{DHV} = 3.5V, V _{DLV} = 0V, V _{DT}	v_ = 1.5V		+60			
DC Output Current		DHV: V _{DLV} = -1V, V _{DHV} / V _{DUT} = 3 and 1.25V / 3.50V	3.50V / 1.25V,	±40			m 4	
De Output Current		DLV: V _{DHV} = 3.5V, V _{DLV} / V _{DUT} = and -1V / +1.25V	+1.25V/-1V	±40			mA	
DC Output Resistance		$I_{DUT} = \pm 20$ mA, $V_{DUT} = V_{DHV} =$	1.25V (Note 3)	48	50	52	Ω	
		$I_{DUT} = \pm 1$ mA, ± 8 mA; $V_{DUT} = V$	DHV_ = 1.25V		0.3	1.0		
DC Output Resistance Variation		$I_{DUT} = \pm 1$ mA, ± 8 mA, ± 15 mA,	MAX9957		1.1	2.0	Ω	
		±40mA; V _{DUT} = V _{DHV} = 1.25V	MAX9957D		1.5	3.0		
		DHV: V _{DHV} = -1V to +3.5V, V _{DLV} = -1V, V _{DTV} = 1.5V DTV: V _{DHV} = 3.5V, V _{DLV} = -1V, V _{DTV} = -1V to +3.5V				±15		
Linearity Error (Note 2)						±15	mV	
		DLV: V _{DHV} = 3.5V, V _{DLV} = -1V to + V _{DTV} = 1.5V			±15			
Power-Supply Rejection Ratio		(Note 4)				±18	mV/V	
DC Crosstalk		(Note 5)				±5	mV	
AC CHARACTERISTICS (ZL = 509	Ω) (Notes 6, 1	7)						
Prop Delay, Data to Output		$V_{DHV} = 2V, V_{DLV} = 0V$	MAX9957	0.75	1.00	1.25	ns	
Trop Delay, Data to Output		(Note 12)	MAX9957D	0.55	0.80	1.05	113	
Prop-Delay Temperature Coefficient					+0.85		ps/°C	
Prop Delay Match, TLH to THL		$V_{DHV} = 2V, V_{DLV} = 0V$ (Note			±100	ps		
Prop Delay Skew, Channel-to- Channel		Same edges (LH and HL)		_	±50	_	ps	
Prop Delay Change Versus Pulse Width		2VP-P, 40MHz, 0.5ns to 24.5ns relative to 12.5ns pulse width		±15		ps		
Prop Delay Change Versus Common-Mode Voltage		$1V_{P-P}, V_{DLV} = -0.5V \text{ to } +2V, \text{ re}$ $V_{DLV} = 0.75V$		±10		ps		



ELECTRICAL CHARACTERISTICS (continued)

 $(V_{CC} = +7V, V_{EE} = -5V, V_L = +3.3V, V_{RTERM} = V_{DTERM} = +3.3V, V_{DHV} = +2V, V_{DLV} = 0V, V_{DTV} = +1V, V_{DOVS} = V_{DOVL} = 0V, T_J = +70^{\circ}C \pm 10^{\circ}C$, unless otherwise noted. All temperature coefficients are measured at T_J = +50^{\circ}C to +90^{\circ}C.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Prop Delay, Data to Term and			MAX9957	0.73	0.98	1.23	
Term to Data		(Note 12)	MAX9957D	0.63	0.88	1.13	ns
		$V_{DHV} = 1V, V_{DTV} = 0.5V,$	MAX9957	80	130	180	
Rise/Fall Time, 1V		$V_{DLV} = 0V, 20\%$ to 80%	MAX9957D	70	120	160	ps
		$V_{DHV} = 2V, V_{DTV} = 1V,$	MAX9957	100	150	200	
Rise/Fall Time, 2V		V _{DLV} = 0V, 20% to 80%	MAX9957D	100	140	190	ps
Minimum Dulao Width 11/		$V_{DHV} = 1V$, $V_{DLV} = 0V$, time to	MAX9957		350	450	50
Minimum Pulse Width, 1V		reach 95% amplitude (Note 12)	MAX9957D		270	370	ps
Minimum Pulse Width, 2V		$V_{DHV} = 2V, V_{DLV} = 0V$, time to	MAX9957		400	500	20
Minimum Fuise Width, 2V		reach 95% amplitude (Note 12)	MAX9957D		300	400	ps
Overshoot		0.5V to 2V swing (Notes 8 and 9		(4% to 25%) + 25		mV	
Input Voltage Range, DOVS_/DOVL_		0V = no peaking, 3.3V = 25% pe	0		3.3	V	
Undershoot		0.5V to 2V swing (Note 9)			1		%
Output Return Loss By TDR		Drive amplitude = $1V$, V_{DLV} = 0 1V, rise time = $150ps (10\% to 90\%)$			5		%
DIFFERENTIAL CONTROL INPL	JTS (DATA_, N	NDATA_, RCV_, and NRCV_)					
Input High Voltage				1.0		3.6	V
Input Low Voltage				0.8		3.4	V
Differential Input Voltage				±0.2		±1.0	V
Voltage Between a Differential Input and its Termination				0		1.9	V
Input Termination Voltage				1.7		3.6	V
Input Termination Resistor				48	50	52	Ω
SINGLE-ENDED INPUTS (DLV_,	DHV_, DTV_,	DOVS_, and DOVL_)					
Input Bias Current						±25	μA
SINGLE-ENDED INPUT (RST)							
Input High Voltage				1.65		3.50	V
Input Low Voltage				-0.10		+0.85	V
Input Bias Current						±50	μA
SINGLE-ENDED OUTPUT (OVL)	(Note 7)						
Digital Supply Voltage	VL			3.00		3.60	V
Digital Supply Current	١L	No load		0.5	1.0	2.0	mA
Output High Voltage		Load current = -1mA		V _L - 0.4		VL	V

ELECTRICAL CHARACTERISTICS (continued)

 $(V_{CC} = +7V, V_{EE} = -5V, V_{L} = +3.3V, V_{RTERM_} = V_{DTERM_} = +3.3V, V_{DHV_} = +2V, V_{DLV_} = 0V, V_{DTV_} = +1V, V_{DOVS_} = V_{DOVL_} = 0V, T_{J} = +70^{\circ}C \pm 10^{\circ}C, unless otherwise noted. All temperature coefficients are measured at T_{J} = +50^{\circ}C to +90^{\circ}C.)$

SYMBOL	CONDITIC	ONS	MIN	ТҮР	МАХ	UNITS
	Load current = 1mA	Load current = 1mA			0.4	V
	10% to 90% (Note 11)			3.6		ns
	(Note 12)		±50		±80	mA
	$T_J = +70^{\circ}C, R_L > 10M\Omega$			3.43		V
				+10		mV/°C
			17	23	29	kΩ
VCC			6.75	7.00	7.50	V
		MAX9957	204	222	240	m ^
ICC		MAX9957D	245	265	285	mA
VEE			-5.50	-5.00	-4.75	V
lee		MAX9957	260	283	306	m ^
IEE		MAX9957D	295	330	360	mA
	four OChoo	MAX9957	2.4	3.0	3.6	W
	1001 = 000bs	MAX9957D	3.05	3.5	4.15	vv
	four OChoo OVa a	MAX9957		3.1		W
	TOUT = 2Gbps, 2VP-P	MAX9957D		3.7		VV
	Vcc	Load current = 1mA 10% to 90% (Note 11) (Note 12) TJ = +70°C, RL > 10MΩ VCC ICC VEE	$\begin{tabular}{ c c c c } \hline Load current = 1mA & & & & & \\ \hline 10\% to 90\% (Note 11) & & & & \\ \hline 10\% to 90\% (Note 11) & & & & \\ \hline (Note 12) & & & & & \\ \hline T_J = +70°C, R_L > 10M\Omega & & & & \\ \hline \hline T_J = +70°C, R_L > 10M\Omega & & & & \\ \hline \hline \hline V_{CC} & & & & & & \\ \hline \hline V_{CC} & & & & & & \\ \hline I_{CC} & & & & & & & \\ \hline I_{CC} & & & & & & & \\ \hline I_{CC} & & & & & & & \\ \hline I_{CC} & & & & & & & \\ \hline I_{CC} & & & & & & & & \\ \hline I_{CC} & & & & & & & & \\ \hline I_{CC} & & & & & & & & \\ \hline I_{CC} & & & & & & & & \\ \hline I_{CC} & & & & & & & \\ \hline I_{CC} & & & & & & & & \\ \hline I_{CC} & & & & & & & & \\ \hline I_{CC} & & & & & & & & \\ \hline I_{CC} & & & & & & & & \\ \hline I_{CC} & & & & & & & & & \\ \hline I_{CC} & & & & & & & & & \\ \hline I_{CC} & & & & & & & & & \\ \hline I_{CC} & & & & & & & & & & \\ \hline I_{CC} & & & & & & & & & & \\ \hline I_{CC} & & & & & & & & & & & \\ \hline I_{CC} & & & & & & & & & & & & \\ \hline I_{CC} & & & & & & & & & & & & \\ \hline I_{CC} & & & & & & & & & & & & \\ \hline I_{CC} & & & & & & & & & & & & & & \\ \hline I_{CC} & & & & & & & & & & & & & & \\ \hline I_{CC} & & & & & & & & & & & & & & \\ \hline I_{CC} & & & & & & & & & & & & & & & & & & $	$\begin{tabular}{ c c c c } \hline Load current = 1mA & 0 \\ \hline 10\% to 90\% (Note 11) & & & & \\ \hline 10\% to 90\% (Note 11) & & & & \\ \hline (Note 12) & & & \pm 50 \\ \hline \\ \hline T_J = +70°C, R_L > 10M\Omega & & & & \\ \hline \\ \hline$	$\begin{tabular}{ c c c c } \hline Load current = 1mA & 0 & & & & \\ \hline 10\% to 90\% (Note 11) & & & 3.6 & & & \\ \hline 10\% to 90\% (Note 11) & & & & & & \\ \hline 10\% to 90\% (Note 11) & & & & & & & \\ \hline 10\% to 90\% (Note 11) & & & & & & & \\ \hline 10\% to 90\% (Note 11) & & & & & & & & \\ \hline 11\% to 12\% & & & & & & & & \\ \hline 11\% to 11$	$\begin{tabular}{ c c c c c } \hline Load current = 1mA & 0 & 0.4 \\ \hline 10\% to 90\% (Note 11) & 3.6 & \\ \hline 10\% to 90\% (Note 11) & \pm 50 & \pm 80 & \\ \hline (Note 12) & \pm 50 & \pm 80 & \\ \hline TJ = +70°C, R_L > 10M\Omega & 3.43 & \\ \hline & & & & & & \\ \hline & & & & & & & \\ \hline & & & &$

Note 1: $R_L \ge 10M\Omega$, unless otherwise noted. All specifications apply to DHV, DLV, and DTV.

Note 2: Relative to a straight line through 0 and 2.5V.

Note 3: Other values of DC output resistance are available on request, contact factory; 45Ω to 51Ω .

Note 4: Change in offset voltage with power supplies independently set to their minimum and maximum values.

Note 5: DC crosstalk is to be measured under six different conditions shown below with the worst case reported:

1) DTV to DHV: V_{DHV} = 3.5V, V_{DLV} = 3.4V, V_{DTV} = -1V to +3.5V (Driver Output: DHV)

2) DTV to DLV: V_{DHV} = -0.9V, V_{DLV} = -1V, V_{DTV} = -1V to +3.5V (Driver Output: DLV)

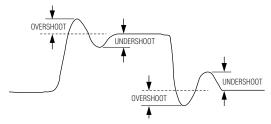
3) DHV to DLV: $V_{DTV} = -1V$, $V_{DLV} = -1V$, $V_{DHV} = -0.9V$ to +3.5V (Driver Output: DLV)

4) DHV to DTV: V_{DTV} = -1V, V_{DLV} = -1V, V_{DHV} = -0.9V to +3.5V (Driver Output: DTV)

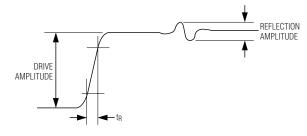
5) DLV to DHV: V_{DHV} = 3.5V, V_{DTV} = 3.5V, V_{DLV} = -1V to +3.4V (Driver Output: DHV)

6) DLV to DTV: V_{DHV} = 3.5V, V_{DTV} = 3.5V, V_{DLV} = -1V to +3.4V (Driver Output: DTV)

- **Note 6:** Load is a terminated 3ns, 50Ω transmission line with 50Ω external termination resistor to GND, unless otherwise specified. Propagation delays are measured from the crossing point of the differential input signals to the 50% point of the expected output swing. Rise time of the differential inputs DATA_ and RCV_ is 300ps (10% to 90%).
- **Note 7:** Guaranteed by design.
- **Note 8:** Driver overshoot setting and output waveform. The voltage range of DOVS_, DOVL_ is 0 to +3.3V, 0 is for no overshoot, and +3.3V is for 25% overshoot, respectively. The fall time of overshoot for DOVS_ (90% to 10%) is 77ps, the fall time of overshoot for DOVL_ (90% to 10%) is 1.5ns.
- Note 9: The definitions of overshoot and undershoot are detailed in this figure:



Note 10: The definition of output return loss by time domain reflectometry (TDR) is: output return loss = (reflection amplitude / drive amplitude) x 100 (%), with terms defined in this figure:

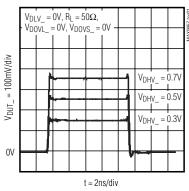


Note 11: Timing characteristics with $V_L = 3.3V$. **Note 12:** Guaranteed by design. Not production tested.

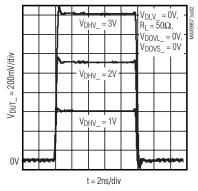
Typical Operating Characteristics (MAX9957)

 $(V_{CC} = +7V, V_{EE} = -5V, V_L = +3.3V, V_{RTERM} = V_{DTERM} = +3.3V, V_{DHV} = +2V, V_{DLV} = 0V, V_{DTV} = +1V, V_{DOVS} = V_{DOVL} = 0V, T_J = +70^{\circ}C \pm 10^{\circ}C$, unless otherwise noted. All temperature coefficients are measured at $T_J = +50^{\circ}C$ to $+90^{\circ}C$.)

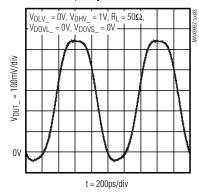
DRIVER SMALL-SIGNAL RESPONSE



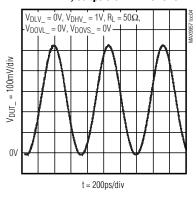
DRIVER LARGE-SIGNAL RESPONSE



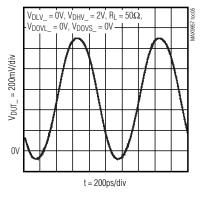
DRIVER 1V, 2Gbps SIGNAL RESPONSE



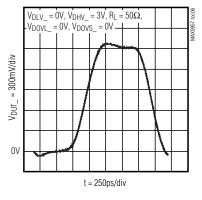
DRIVER 1V, 3Gbps SIGNAL RESPONSE



DRIVER 2V, 2Gbps SIGNAL RESPONSE

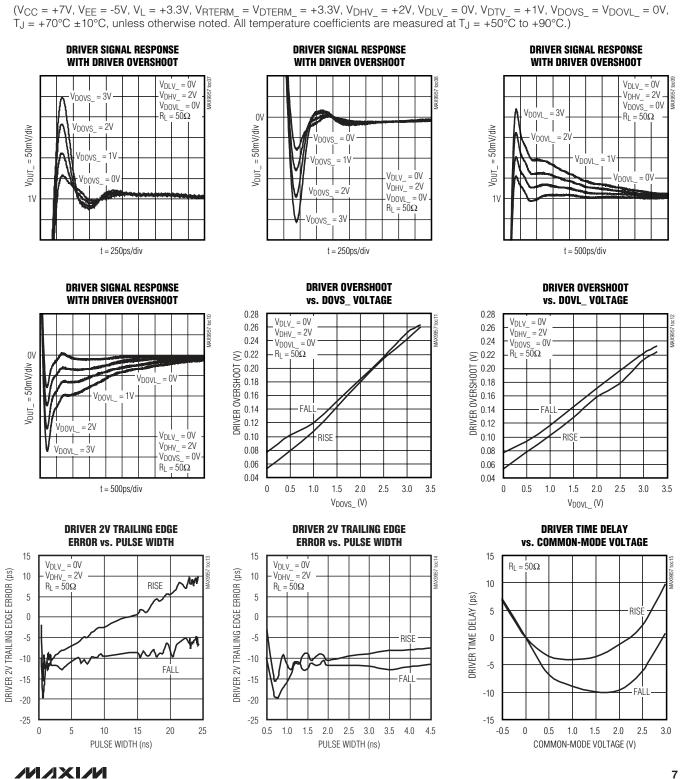


DRIVER 3V, 1Gbps SIGNAL RESPONSE

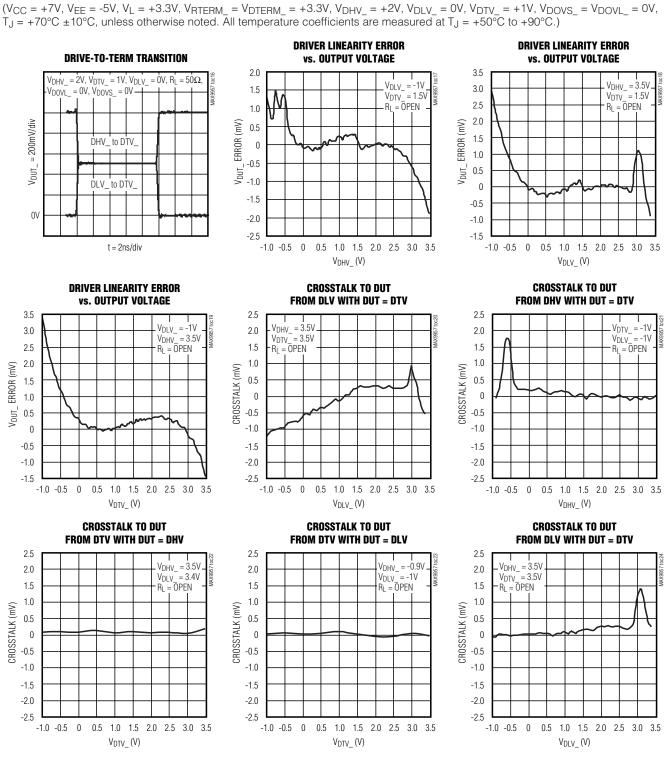




Typical Operating Characteristics (MAX9957) (continued)



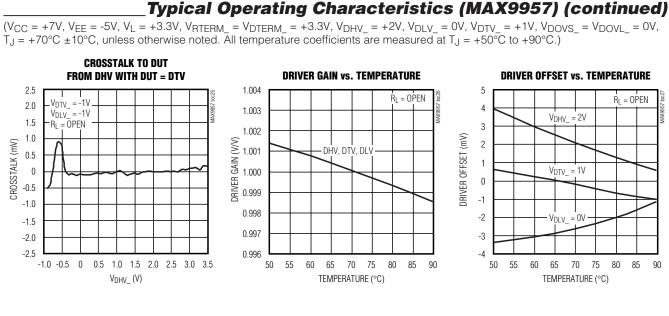
MAX995



MIXIM

Typical Operating Characteristics (MAX9957) (continued)

MAX9957



SUPPLY CURRENT, I_{CC} vs. SUPPLY VOLTAGE, V_{CC}

240

236

232

228

E 224

216

212

208

204

6.75

 $V_{DHV1} = V_{DHV2} = 2V$,

 $V_{DTV1} = V_{DTV2} = 1V$,

 $V_{DLV1} = V_{DLV2} = 0V$,

6.95

7.05

V_{CC} (V)

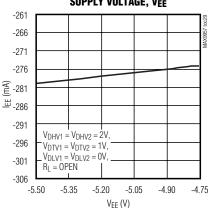
7.15

7.25

R_L = OPEN

6.85

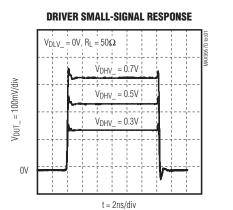


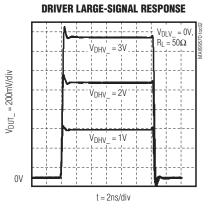




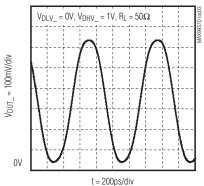
Typical Operating Characteristics (MAX9957D)

 $(V_{CC} = +7V, V_{EE} = -5V, V_L = +3.3V, V_{RTERM} = V_{DTERM} = +3.3V, V_{DHV} = +2V, V_{DLV} = 0V, V_{DTV} = +1V, V_{DOVS} = V_{DOVL} = 0V, T_J = +70^{\circ}C \pm 10^{\circ}C$, unless otherwise noted. All temperature coefficients are measured at $T_J = +50^{\circ}C$ to $+90^{\circ}C$.)

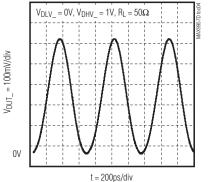




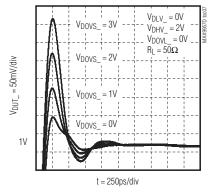
DRIVER 1V, 2.4Gbps SIGNAL RESPONSE

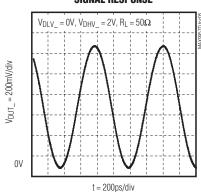


DRIVER 1V, 3Gbps SIGNAL RESPONSE



DRIVER SIGNAL RESPONSE WITH DRIVER OVERSHOOT





DRIVER SIGNAL RESPONSE

WITH DRIVER OVERSHOOT

 $V_{DOVS} = 0V$

 $V_{DOVS} = 1V$

 $V_{DOVS} = 2V$

 $V_{DOVS} = 3V$

t = 250ps/div

 $V_{DLV} = 0V$

 $V_{DHV} = 2V$

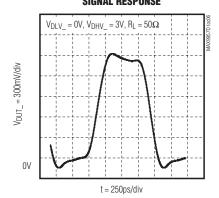
 $V_{DOVL} = 0V$ $R_L = 50\Omega$

0V

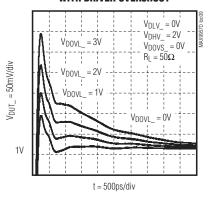
 $V_{DUT} = 50 mV/div$

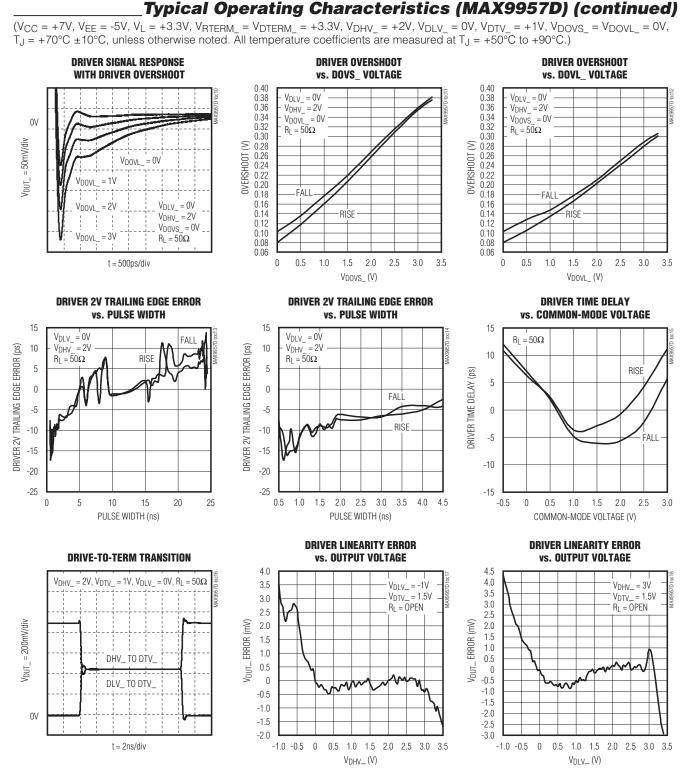
DRIVER 2V, 2.4Gbps Signal Response

DRIVER 3V, 1Gbps SIGNAL RESPONSE



DRIVER SIGNAL RESPONSE WITH DRIVER OVERSHOOT

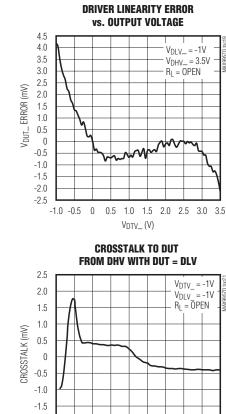


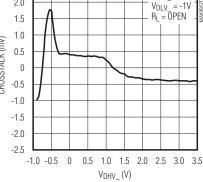


MAX995

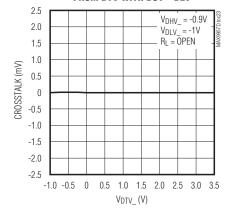
Typical Operating Characteristics (MAX9957D) (continued)

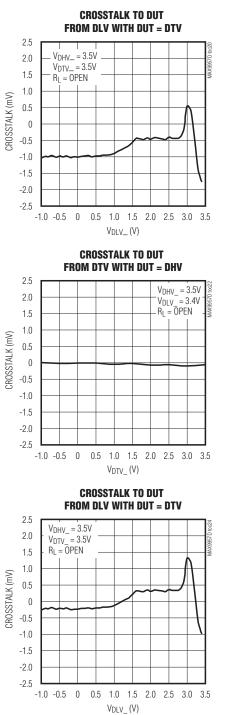
 $(V_{CC} = +7V, V_{EE} = -5V, V_L = +3.3V, V_{RTERM} = V_{DTERM} = +3.3V, V_{DHV} = +2V, V_{DLV} = 0V, V_{DTV} = +1V, V_{DOVS} = V_{DOVL} = 0V, T_J = +70^{\circ}C \pm 10^{\circ}C$, unless otherwise noted. All temperature coefficients are measured at T_J = +50^{\circ}C to +90^{\circ}C.)





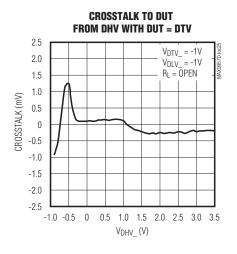
CROSSTALK TO DUT FROM DTV WITH DUT = DLV



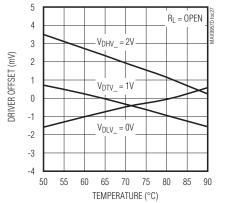


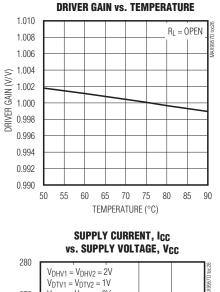
Typical Operating Characteristics (MAX9957D) (continued)

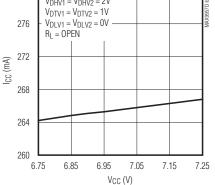
 $(V_{CC} = +7V, V_{EE} = -5V, V_L = +3.3V, V_{RTERM} = V_{DTERM} = +3.3V, V_{DHV} = +2V, V_{DLV} = 0V, V_{DTV} = +1V, V_{DOVS} = V_{DOVL} = 0V, T_J = +70^{\circ}C \pm 10^{\circ}C$, unless otherwise noted. All temperature coefficients are measured at $T_J = +50^{\circ}C$ to $+90^{\circ}C$.)



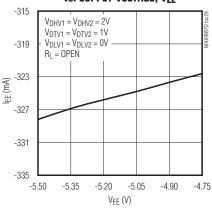
DRIVER OFFSET vs. TEMPERATURE











MAX9957

MAX9957

		Pin Description
PIN	NAME	FUNCTION
1, 5, 7, 10, 12, 16, 20, 32, 33, 48, 49, 61	VEE	Negative Power Supply
2, 4, 8, 9, 13, 15, 21, 23, 31, 50, 58, 60	Vcc	Positive Power Supply
3, 14, 17, 19, 22, 30, 34, 47, 51, 59, 62, 64	GND	Ground
6	DUT1	Driver 1 Output
11	DUT2	Driver 2 Output
18	TEMP	Temperature Monitor Output
24	RST	Reset Input. Reset for the overcurrent detector. Clears the OVL output.
25	DOVL2	Driver Overshoot Voltage-Control Input, Long. Setting for DC waveform shaping for long-term overshoot of channel 2.
26	DOVS2	Driver Overshoot Voltage-Control Input, Short. Setting for DC waveform shaping for short-term overshoot of channel 2.
27	DTV2	Driver Term Voltage Input. DC input voltage for channel 2.
28	DHV2	Driver High Voltage Input. DC input voltage for channel 2.
29	DLV2	Driver Low Voltage Input. DC input voltage for channel 2.
35	NDATA2	Multiplexer 2 Data Negative Control Input. NDATA and DATA form the differential multiplexer inputs that select between DHV and DLV for channel 2.
36	DATA2	Multiplexer 2 Data Positive Control Input. DATA and NDATA form the differential multiplexer inputs that select between DHV and DLV for channel 2.
37	DTERM2	Data Termination 2 Voltage Input. Termination voltage connection for DATA/NDATA input termination resistors of channel 2.
38	NRCV2	Multiplexer 2 Receive Negative Control Input. NRCV and RCV form the differential multiplexer inputs that select between DTV and DHV/DLV for channel 2.
39	RCV2	Multiplexer 2 Receive Positive Control Input. RCV and NRCV form the differential multiplexer inputs that select between DTV and DHV/DLV for channel 2.
40	RTERM2	Receive Termination 2 Voltage Input. Termination voltage connection for channel 2 RCV/NRCV input termination resistors.
41	RTERM1	Receive Termination 1 Voltage Input. Termination voltage connection for channel 1 RCV/NRCV input termination resistors.
42	RCV1	Multiplexer 1 Receive Positive Control Input. RCV and NRCV form the differential multiplexer inputs that select between DTV and DHV/DLV for channel 1.
43	NRCV1	Multiplexer 1 Receive Negative Control Input. NRCV and RCV form the differential multiplexer inputs that select between DTV and DHV/DLV for channel 1.



Pin Description (continued)

PIN	NAME	FUNCTION			
44	DTERM1	Data Termination 1 Voltage Input. Termination voltage connection for DATA/NDATA input termination resistors of channel 1.			
45	DATA1	Multiplexer 1 Data Positive Control Input. DATA and NDATA form the differential multiplexer inputs that select between DHV and DLV for channel 1.			
46	46 NDATA1 Multiplexer 1 Data Negative Control Input. NDATA and DATA form the differential multi that select between DHV and DLV for channel 1.				
52	DLV1	Driver Low Voltage Input. DC input voltage for channel 1.			
53	DHV1	Driver High Voltage Input. DC input voltage for channel 1.			
54	DTV1	Driver Term Voltage Input. DC input voltage for channel 1.			
55	DOVS1	Driver Overshoot Voltage-Control Input, Short. Setting for DC waveform shaping for short-term overshoot of channel 1.			
56	DOVL1	Driver Overshoot Voltage-Control Input, Long. Setting for DC waveform shaping for long-term overshoot of channel 1.			
57	VL	Logic Power-Supply Input			
63	OVL	Overcurrent Detect Output. Clear OVL with the RST input.			
_	EP	Exposed Pad for Heat Removal. Internally connected to V_{EE} . Connect to V_{EE} or leave unconnected. Do not use as the primary V_{EE} connection.			

Detailed Description

The MAX9957 dual driver IC for ATE features voltagecontrolled waveform shaping to enhance edge-placement accuracy and minimize distortion. The MAX9957 offers three-level drive capability, high-speed switching, and low timing dispersion. Input reference voltages are buffered for each channel and have nominal -1V to +3.5V voltage ranges. Static power dissipation is only 1500mW per channel, with nominal -5V and +7V supplies, and power dissipation at 2Gbps toggling is only 1550mW/channel. Figure 1 shows a functional diagram of the MAX9957.

The Driver

The driver input is a high-speed multiplexer that selects one of three voltage inputs: DHV_, DLV_, or DTV_. High-speed inputs DATA_/NDATA_ and RCV_/NRCV_ control the switching of the multiplexer, as shown in Table 1. The differential control inputs are compatible with ECL, LVPECL, LVDS, and GTL logic.

Table 1. Driver Logic

	OUTPUT			
DATA_	NDATA_	RCV_	UUIFUI	
L	Н	L	Н	Driver to DLV
н	L	L	Н	Driver to DHV
х	Х	Н	L	Driver to DTV

X = Don't care.

The nominal driver output resistance is 50 Ω . Contact the factory for different resistance values between 45 Ω and 51 Ω .

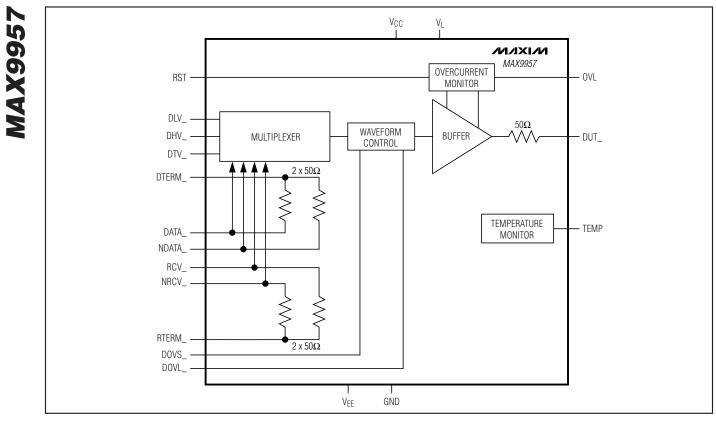


Figure 1. Functional Diagram

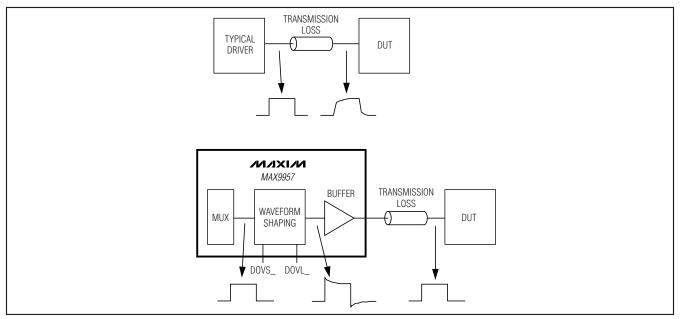


Figure 2. Waveform Shaping

Waveform Shaping

The driver incorporates active waveform shaping. At high frequencies, transmission line effects degrade the output waveform fidelity as the signal travels from DUT to the device under test. The waveform-shaping circuit compensates for this degradation by adding two single time-constant decaying waveforms to the nominal output waveform. Figure 2 depicts a comparison between a typical driver and the MAX9957, and shows how waveform shaping compensates for cable transmission degradation. In the frequency domain, the nominal output function is multiplied by two zero-pole pairs. Analog voltage inputs DOVS_ (short) and DOVL_ (long) control the peaking amplitude. Table 2 details the input levels for peaking amplitude control. The time constants are fixed. DOVS_ varies the amplitude of the high-frequency boost (77ps (typ) time constant), while DOVL_ varies the amplitude of the low-frequency boost (1.5ns (typ) time constant). See the Typical Operating Characteristics for peaking versus DOVS_ and DOVL_ voltages. Connect DOVS_ and DOVL_ to GND if compensation is not required.

Overcurrent Detection

The MAX9957 monitors the buffer output current. If the current exceeds the overcurrent detect threshold, the output current is reduced and OVL latches high. Overcurrent detection is only a safety feature and not a trimmed or production-tested specification. The detection window is \pm 50mA to \pm 80mA and post-detection current is reduced to between \pm 20mA and \pm 30mA. Assert RST to return the buffer to normal operation and reset OVL. The single RST input controls both channels.

Temperature Monitor

The MAX9957 supplies a temperature output signal (TEMP) that provides a nominal output voltage of 3.43V at a die temperature of 343K (+70°C). VTEMP changes proportionally with temperature at 10mV/°C.

Chip Information

PROCESS: Bipolar

Table 2. Waveform Shaping Control Inputs

INF	TUY	OUTPUT
DOVS_	DOVL_	OUIPUI
OV	OV	Overshoot off
OV	0 to 3.3V	Overshoot (long)
0 to 3.3V	0V	Overshoot (short)
0 to 3.3V	0 to 3.3V	Overshoot (long + short)

Table 3. Overcurrent Detection

L	OGIC INP	UTS	LOGIC OUTPUT	DRIVER	ουτρυτ
RST	OVERCURRENT DETECTION		OVL	BUFFEI	RMODE
	DUT1	DUT2		DUT1	DUT2
Х	\uparrow	0	Н	Off	On
X	0	\uparrow	Н	On	Off
Х	\uparrow	\uparrow	Н	Off	Off
1	1	0	Н	Off	On
\uparrow	0	1	Н	On	Off
\uparrow	1	1	Н	Off	Off
↑	0	0	L	On	On

X = Don't care.

 \uparrow = Rising edge.

Applications Information

Heat Removal

Under normal circumstances, the MAX9957 requires heat removal through the exposed pad by use of an external heat sink. The exposed pad is electrically at VEE potential. The heatsink must be connected to VEE, or electrically isolated from the exposed pad.

Power-Supply Considerations

Bypass all V_{CC}, V_{EE}, and V_L power-supply inputs each with a 0.01µF capacitor and use bulk bypassing of at least 10µF on each supply where power enters the board.

Package Information

For the latest package outline information and land patterns, go to **www.maxim-ic.com/packages**. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE TYPE	PACKAGE CODE	DOCUMENT NO.
64 TQFP-EPR	C64E-9R	<u>21-0162</u>

Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	8/07	Initial release	—
1	3/10	Added MAX9957D specifications to data sheet	1–4, 6, 7, 10–13

Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

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